

	Type	L #	Hits	Search Text	DBs
1	BRS	L1	0	372/46.ccls. and (ridge same contact same (p near electrode) same (intermediate buffer insulator) same diffus\$3)	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B
2	BRS	L2	0	372/46.ccls. and (ridge same contact same (p near electrode) same (intermediate buffer insulator))	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B
3	BRS	L3	0	372/46.ccls. and (ridge same contact same electrode same (intermediate buffer insulator) same diffus\$3)	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B
4	BRS	L4	2	372/46.ccls. and (ridge same contact same electrode same (intermediate buffer insulator))	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B

	Time Stamp	Comments	Error Definition	Errors
1	2005/09/19 16:01			
2	2005/09/19 16:01			
3	2005/09/19 16:02			
4	2005/09/19 16:03			

	Type	L #	Hits	Search Text	DBs
5	BRS	L5	10	372/46.ccls. and ((ridge strip\$) same contact same electrode same (intermediate buffer insulator))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB
6	BRS	L6	35	372/43.ccls. and ((ridge strip\$) same contact same electrode same (intermediate buffer insulator))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB
7	BRS	L7	2	372/44.ccls. and ((ridge strip\$) same contact same electrode same (intermediate buffer insulator))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB
8	BRS	L8	1892	((ridge strip\$) same contact same electrode same (intermediate buffer insulator))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB

	Time Stamp	Comments	Error Definition	Errors
5	2005/09/19 16:06			
6	2005/09/19 16:19			
7	2005/09/19 16:20			
8	2005/09/19 16:20			

	Type	L #	Hits	Search Text	DBs
9	BRS	L9	313	((ridge strip\$) same contact same electrode same (intermediate buffer insulator)) same (semiconductor adj laser)	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B
10	BRS	L10	31	((ridge strip\$) same contact same (p near electrode) same (intermediate buffer insulator)) same (semiconductor adj laser)	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B
11	BRS	L11	2	((ridge strip\$) same contact same (p near electrode) same (intermediate buffer insulator)) same (semiconductor adj laser).clm.	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B
12	BRS	L12	33	((ridge strip\$) same (ohmic contact) same (p near electrode) same (intermediate buffer insulator)) same (semiconductor adj laser)	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B

	Time Stamp	Comments	Error Definition	Errors
9	2005/09/19 16:20			
10	2005/09/19 16:37			
11	2005/09/19 16:39			
12	2005/09/19 16:39			

	Type	L #	Hits	Search Text	DBs
13	BRS	L13	4	((ridge strip\$) same ohmic same (p near electrode) same (intermediate buffer insulator)) same (semiconductor adj laser)	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B
14	BRS	L14	988	372/46.ccls.	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B
15	BRS	L15	10	114 and ((intermediate insulat\$3 buffer) with (contact same electrode))	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B
16	BRS	L16	44	372/43.ccls. and ((intermediate insulat\$3 buffer) with (contact same electrode))	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B

	Time Stamp	Comments	Error Definition	Errors
13	2005/09/19 16:41			
14	2005/09/19 16:41			
15	2005/09/19 16:46			
16	2005/09/19 16:57			

	Type	L #	Hits	Search Text	DBs
17	BRS	L17	3	372/44.ccls. and ((intermediate insulat\$3 buffer) with (contact same electrode))	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B
18	BRS	L18	20	372/45.ccls. and ((intermediate insulat\$3 buffer) with (contact same electrode))	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B
19	BRS	L19	14915	(intermediate insulator) with diffus\$3	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B
20	BRS	L20	7579	((intermediate insulator) with layer) with diffus\$3	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B

	Time Stamp	Comments	Error Definition	Errors
17	2005/09/19 16:58			
18	2005/09/19 17:58			
19	2005/09/19 18:00			
20	2005/09/19 18:00			

	Type	L #	Hits	Search Text	DBs
21	BRS	L21	27	((intermediate insulator) with layer) with diffus\$3) same (semiconductor adj laser)	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B
22	BRS	L22	51	((intermediate adj layer) with (buffer adj layer)) same (semiconductor adj laser)	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B
23	BRS	L23	22	((intermediate adj layer) with (buffer adj layer)) same adhesi\$2	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B

	Time Stamp	Comments	Error Definition	Errors
21	2005/09/19 18:17			
22	2005/09/19 18:18			
23	2005/09/19 18:18			